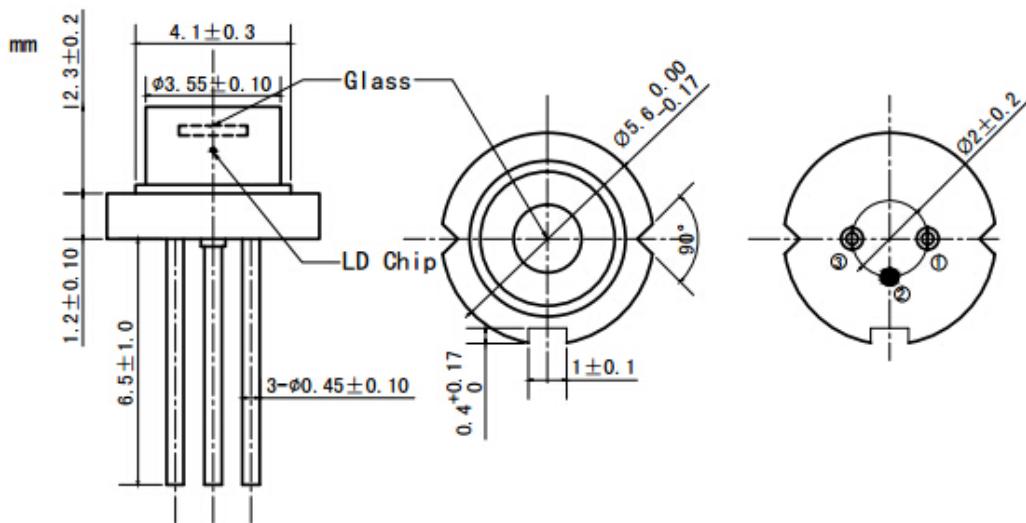
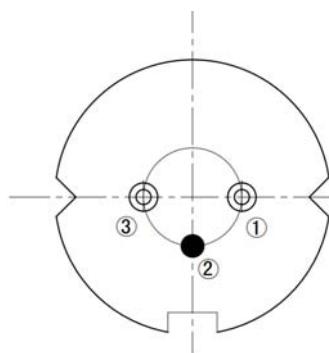


808nm 500mW Laser Diodes with 5.6mm Package | Infrared Laser Diode
808nm~810nm LD 500mW with TO18 Package | Built-in PD
RWSLD-808-500m-1-PD

808nm Laser Diode 500mW/TO18		en.wavespectrum-laser.com.cn	
Reverse Voltage	V_r	2.0	V
Operating Temperature	T_{op}	-20~+60	°C
Storage Temperature	T_{stg}	-40~+80	°C
Lead soldering temperature (10 sec.)	T_{ls}	260	°C
Features:	<ul style="list-style-type: none"> ● 808nm ● CW ● TO18 Package ● Built-in PD 		
Applications:	<ul style="list-style-type: none"> ● Medical Laser Treatment ● Night Vision ● Others 		
Specifications	RWSLD-808-500m-1-PD		
	Min	Type	Max
Center Wavelength@25°C	808nm±10nm		
Spectral Width (FWHM)	----	2.5nm	----
Output Power	----	500mW	----
Recommended Work Temperature	25°C		
Beam Divergence (FWHM)	----	35° \perp x 10°//	----
Slope Efficiency	----	1.1mW/mA	----
Threshold Current (Typ.)	----	70mA	100mA
Operating Current (Typ.)	----	550mA	600mA
Operating Voltage	----	2.0V	2.4V
Package Style	TO18		



TO18(5.6mm) Package View

PIN Bottom View:


1	LD(-)
2	LD(+) & PD(+)
3	PD(+)

Electrically shorten LD module and store in non-extreme conditions.

Suggest using the constant current power supply.

